**Product data sheet** 

### 1. General description

Planar passivated SCR with faster switching performance and sensitive gate in a SOT223 surface mounted plastic package. This SCR with enhanced commutation performance is also designed to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

#### 2. Features and benefits

- Fast commutation performance for higher frequency operation
- Full wave rectified AC applications
- Sensitive gate
- · Direct triggering from microcontrollers, low power drivers and logic ICs

### 3. Applications

- Earth leakage circuit breakers (ELCB/GFI)
- · Ignition circuits (gas appliances, small engines and HID lighting)

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	-	600	V
$I_{T(AV)}$	average on-state current	half sine wave; T <sub>sp</sub> ≤ 112 °C; <u>Fig. 1</u>	-	-	0.63	Α
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; $T_{sp} \le 112 ^{\circ}\text{C}$ ; Fig. 2; Fig. 3	-	-	1	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5	-	-	8	Α
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	-	-	9	A
Tj	junction temperature		-	-	125	°C
Static charact	eristics					
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; I_T = 10 \text{ mA}; T_j = 25 \text{ °C};$ Fig. 9	70	200	450	μA
Dynamic char	acteristics			•		
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; $T_j$ = 125 °C; $R_{GK}$ = 1 kΩ; $(V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; Fig. 11	350	800	-	V/µs

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		$V_{DM}$ = 402 V; $T_j$ = 125 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; gate open circuit; Fig. 11	-	25	-	V/µs

## 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	4	А <del>-    </del> К
2	Α	anode		G sym037
3	G	gate		symosi
4	mb	mb; connected to anode	⊟1 ⊟2 ⊟3 SC-73 (SOT223)	

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package				
	Name	Description	Version		
BT168GWF	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223		

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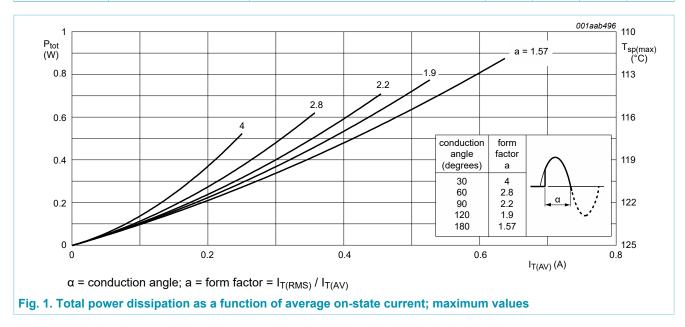
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## 7. Limiting values

### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DRM}$	repetitive peak off-state voltage		-	600	V
$V_{RRM}$	repetitive peak reverse voltage		-	600	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>sp</sub> ≤ 112 °C; <u>Fig. 1</u>	-	0.63	Α
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>sp</sub> ≤ 112 °C; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	1	Α
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5	-	8	Α
		half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 8.3 ms	-	9	Α
I <sup>2</sup> t	I <sup>2</sup> t for fusing	$t_p$ = 10 ms; SIN	-	0.32	A²s
dl <sub>T</sub> /dt	rate of rise of on-state current	$I_T = 2 \text{ A}$ ; $I_G = 10 \text{ mA}$ ; $dI_G/dt = 100 \text{ mA/}\mu\text{s}$	-	50	A/µs
I <sub>GM</sub>	peak gate current		-	1	Α
$V_{RGM}$	peak reverse gate voltage		-	5	V
P <sub>GM</sub>	peak gate power		-	2	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.1	W
T <sub>stg</sub>	storage temperature		-40	150	°C
T <sub>j</sub>	junction temperature		-	125	°C



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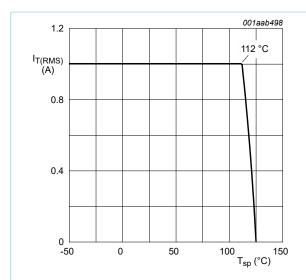


Fig. 2. RMS on-state current as a function of solder point temperature; maximum values

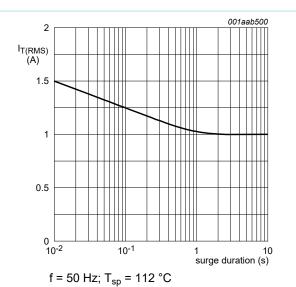


Fig. 3. RMS on-state current as a function of surge duration; maximum values

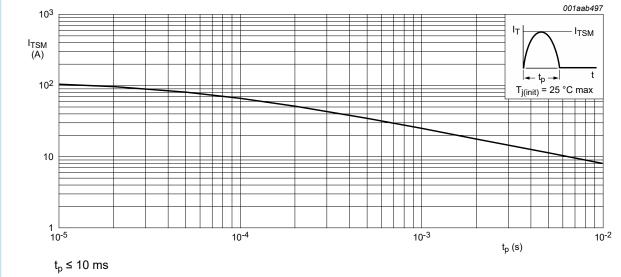


Fig. 4. Non-repetitive peak on-state current as a function of pulse width for sinusoidal currents; maximum values

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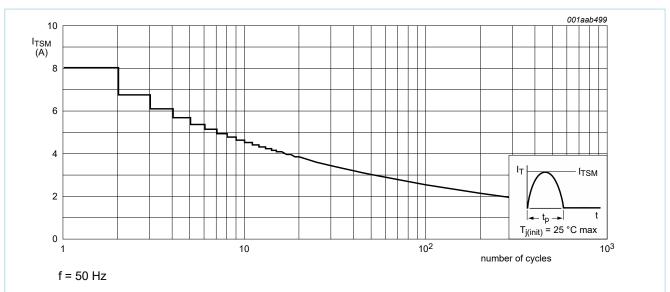


Fig. 5. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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### 8. Thermal characteristics

**Table 5. Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point	Fig. 6	-	-	15	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to	printed-circuit board mounted; minimum footprint; Fig. 7	-	156	-	K/W
	ambient free air	printed-circuit board mounted; pad area; Fig. 8	-	70	-	K/W

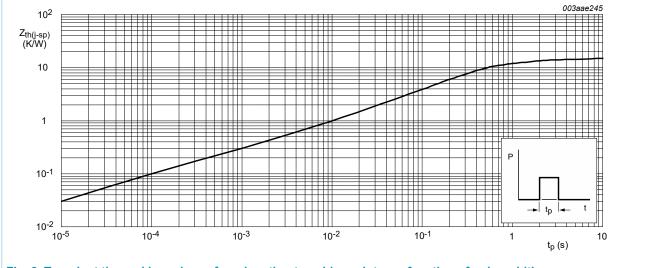
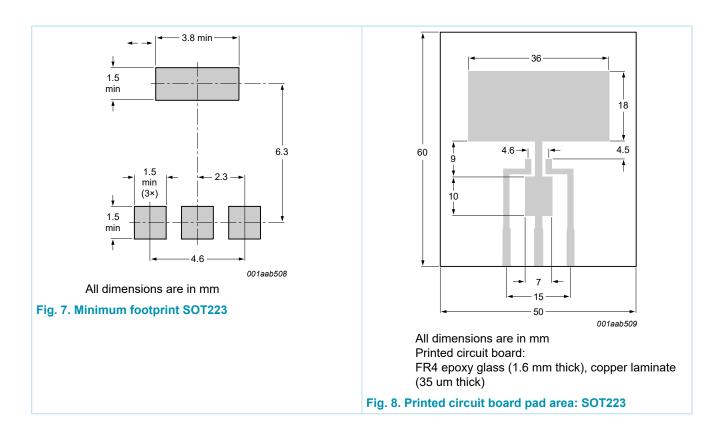


Fig. 6. Transient thermal impedance from junction to solder point as a function of pulse width

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### 9. Characteristics

**Table 6. Characteristics** 

Table 6. Chara	Cleristics						
Symbol	Parameter	Conditions	N	<b>/</b> lin	Тур	Max	Unit
Static charact	teristics						
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; I_T = 10 \text{ mA}; T_j = 25 \text{ °C};$ Fig. 9	7	70	200	450	μΑ
IL	latching current	$V_D$ = 12 V; $I_G$ = 0.5 mA; $T_j$ = 25 °C; $R_{GK(ext)}$ = 1 k $\Omega$	3	3	7.5	13	mA
I <sub>H</sub>	holding current	$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; R_{GK(ext)} = 1 \text{ k}\Omega$	C	).5	4.1	10	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 1.2 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-		1.35	1.7	V
$V_{GT}$	gate trigger voltage	$V_D = 12 \text{ V}; I_T = 10 \text{ mA}; T_j = 25 ^{\circ}\text{C}$	-		0.5	0.8	V
		V <sub>D</sub> = 600 V; I <sub>T</sub> = 10 mA; T <sub>j</sub> = 125 °C	C	).2	0.3	-	V
I <sub>D</sub>	off-state current	$V_D = 600 \text{ V}; R_{GK(ext)} = 1 \text{ k}\Omega; T_j = 125 \text{ °C}$	-		0.05	0.1	mA
I <sub>R</sub>	reverse current	$V_R = 600 \text{ V}; T_j = 125 \text{ °C}; R_{GK(ext)} = 1 \text{ k}\Omega$	-		0.05	0.1	mA
Dynamic chai	racteristics						
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; $T_j$ = 125 °C; $R_{GK}$ = 1 kΩ; $(V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; Fig. 11	3	350	800	-	V/µs
		$V_{DM}$ = 402 V; $T_j$ = 125 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; gate open circuit; Fig. 11	-		25	-	V/µs

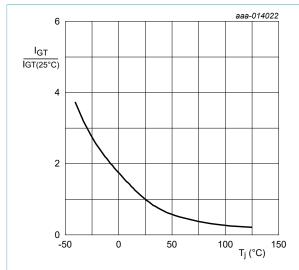


Fig. 9. Normalized gate trigger current as a function of junction temperature

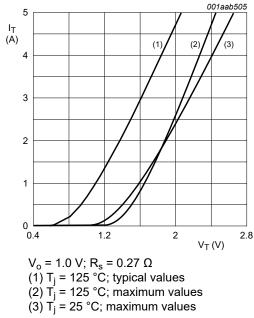
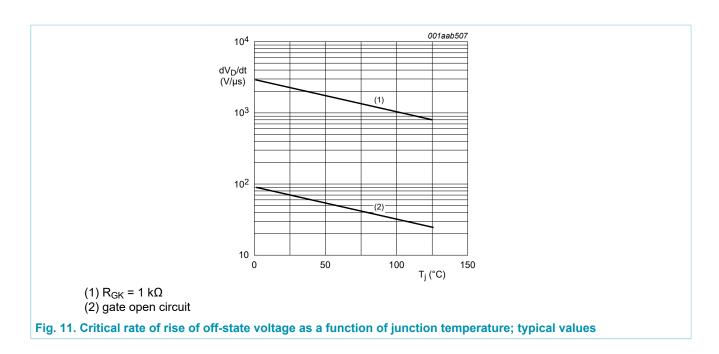


Fig. 10. On-state current as a function of on-state voltage

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## 10. Package outline

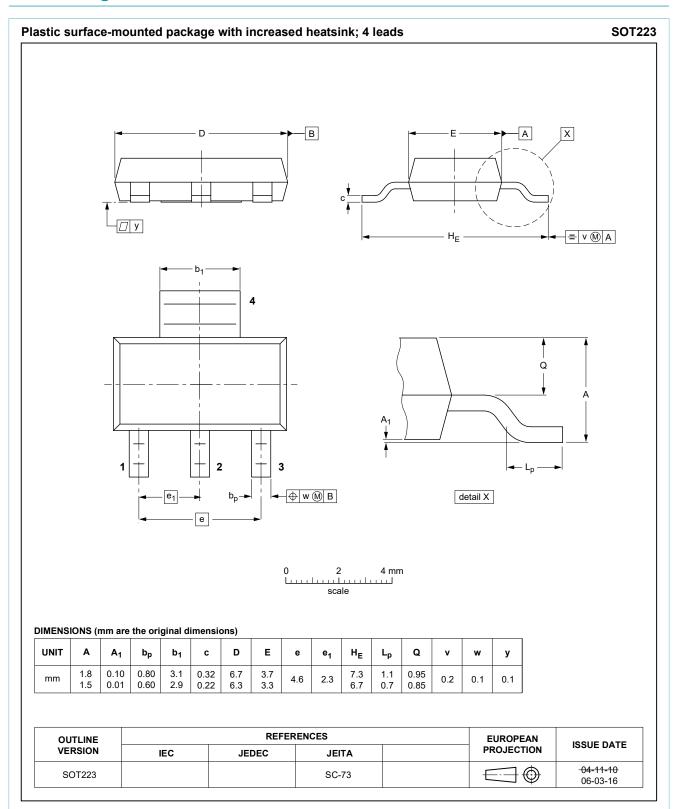
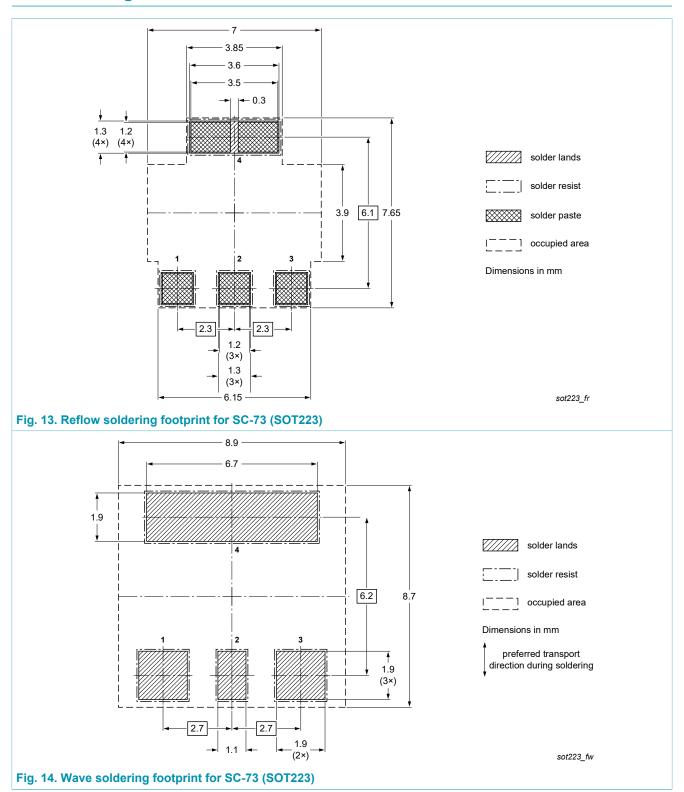


Fig. 12. Package outline SC-73 (SOT223)

### 11. Soldering



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BT168GWF

## 12. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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